Apacer

The Most **Reliable** Storage For Industries

SM23D-25







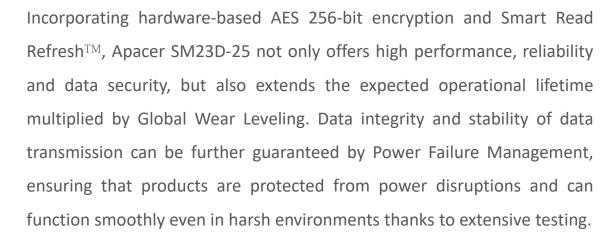
Apacer

SM25D-25

Overview

Tailor-made Rugged Solutions for Rugged Applications

Apacer SM23D is a series of rugged, defense-grade solid-state drives and modules specifically designed for rugged applications to protect highly sensitive data.







Multiple Protection Technologies that Safeguard Sensitive Data

In addition to the aforementioned built-in implementations, Apacer SM23D-25 provides a wide range of optional solutions and cutting-edge technologies featuring multiple approaches to protection, including TCG Opal 2.0/SED, Instant KeychangeTM, MIL Erase, Digital Destruction and Write Protect. These security features can be triggered either via software or hardware methods, except TCG Opal 2.0 which can only be activated via software commands. With these technologies available for employment, mission-critical data is safeguarded against unauthorized access at all times and no data will be compromised as Apacer SM23D-25 adheres to MIL compliance standards.



Withstood 8 Tough US DoD Military Standard Tests

Apacer SM23D-25 is a combination of the latest firmware, software and hardware technologies that guarantee that rugged solutions are perfectly customized and engineered for customers' requirements. The US Department of Defense has a complex series of MIL standards. The SM23D rugged series has passed their tests that cover:

- 1. Shock
- **2. Vibration:** Reaches the highest requirements of MIL-STD 810G 514.6 for Fixed Wing Jet Aircraft.
- 3. Humidity
- 4. High/Low Temp.
- **5. Thermal Shock:** Exposes components to high and low temperatures that cycle rapidly.
- **6. Altitude:** Simulates the effects of high pressure in an aircraft flying at 80,000 feet.
- **7. Salt Fog:** Uses a five percent salt spray to simulate accelerated corrosion in a relatively slow airflow environment.
- **8. Radiation:** Simulates the full-spectrum interference environment that heat and sunlight can create.



Shock

MIL-STD-202G MIL-STD-883K

Thermal Shock

MIL-STD-810G Method 503.5 Procedure I-C

Vibration

MIL-STD-810G

Altitude

MIL-STD-810G Method 500.5

Humidity

MIL-STD-810G Method 507.5

Salt fog

MIL-STD-810G Method 509.5

High/ Low Temp.

MIL-STD-810G Method 501.5 MIL-STD-810G Method 502.5

Radiation Test

MIL-STD-810G Method 505.5 procedur 2

Feature

- SM23D rugged series
- Supports TCG Opal 2.0 / AES 256-bit encryption
- Global Wear Leveling
- Power Failure Management

S.M.A.R.T.

ATA Secure Erase

- TRIM
- Mechanical design available in 9.5mm height

• SMART Read RefreshTM

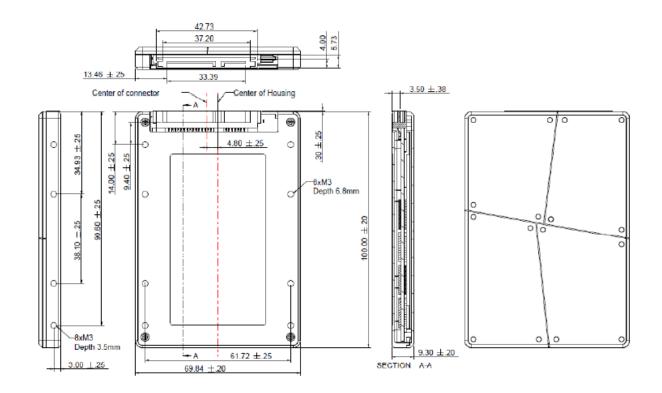


Specifications

Model SM23D-25 Interface SATA 3.2 (66b/s) Connector (7+15) pin Form Factor 2.5" NAND Flash Type MLC Capacity With AES 256 support: 32GB*1TB With TCG Opal 2.0 support: 32GB*512GB External DRAM No Sustained Read Performance (MB/sec) Up to 560 Sustained Write Performance (MB/sec) Up to 510 ECC Engine Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (*C) 0 ~ + 70 Wide Temperature (*C) -40 ~ + 85 Storage Temperature (*C) -55 ~ + 100 Shock MIL-STD-202G, Condition A MIL-STD-83K, Condition B Vibration MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm) MTBF (hours) >5,000,000		
Connector Form Factor 2.5" NAND Flash Type MLC With AES 256 support: 32GB~1TB With TCG Opal 2.0 support: 32GB~512GB External DRAM No Sustained Read Performance (MB/sec) Up to 560 Sustained Write Performance (MB/sec) Up to 510 ECC Engine Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (°C) Wide Temperature (°C) -55~+100 Shock MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage FV ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Model	SM23D-25
Form Factor NAND Flash Type MLC With AES 256 support: 32GB~1TB With TCG Opal 2.0 support: 32GB~512GB External DRAM No Sustained Read Performance (MB/sec) Up to 560 Sustained Write Performance (MB/sec) Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 55K Standard Operating Temperature (°C) Wide Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-830K, Condition B Will-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V±10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Interface	SATA 3.2 (6Gb/s)
MAND Flash Type MLC With AES 256 support: 32GB~1TB With TCG Opal 2.0 support: 32GB~512GB External DRAM No Sustained Read Performance (MB/sec) Up to 560 Sustained Write Performance (MB/sec) Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (°C) Wide Temperature (°C) Storage Temperature (°C) MIL-STD-202G, Condition A MIL-STD-83K, Condition B Will-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V±10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Connector	(7+15) pin
Capacity With AES 256 support: 32GB~1TB With TCG Opal 2.0 support: 32GB~512GB External DRAM No Sustained Read Performance (MB/sec) Up to 560 Sustained Write Performance (MB/sec) Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (°C) Wide Temperature (°C) Storage Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage SV ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Form Factor	2.5"
External DRAM No Sustained Read Performance (MB/sec) FUD to 560 Sustained Write Performance (MB/sec) ECC Engine Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) Standard Operating Temperature (°C) Wide Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage Power Consumption Michage Standard Idle mode: 100 mA Dimension (L x W x H) No Up to 560 Up to 560 Up to 510 MID-STD Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) Up to 560 Up to 560 Wip to 510 Active mode: 590 mA / Idle mode: 100 mA	NAND Flash Type	MLC
Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (°C) Wide Temperature (°C) Storage Temperature (°C) -40 ~ + 85 Storage Temperature (°C) MIL-STD-202G, Condition A MIL-STD-83K, Condition B MIL-STD-83K, Condition B Wibration MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Capacity	· ·
Sustained Write Performance (MB/sec) ECC Engine Low-Density Parity-Check (LDPC) Code IOPS (4K Random Write) 65K Standard Operating Temperature (°C) Wide Temperature (°C) -40~+85 Storage Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-820G, Condition B MIL-STD-83K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	External DRAM	No
ECC Engine Low-Density Parity-Check (LDPC) Code 1OPS (4K Random Write) Standard Operating Temperature (°C) Wide Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Sustained Read Performance (MB/sec)	Up to 560
IOPS (4K Random Write) Standard Operating Temperature (°C) 0 ~ + 70 Wide Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Sustained Write Performance (MB/sec)	Up to 510
Standard Operating Temperature (°C) Wide Temperature (°C) Storage Temperature (°C) Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage SV ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	ECC Engine	Low-Density Parity-Check (LDPC) Code
Wide Temperature (°C) -40~+85 Storage Temperature (°C) -55~+100 MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	IOPS (4K Random Write)	65K
Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Standard Operating Temperature (°C)	0~+70
Shock MIL-STD-202G, Condition A MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Wide Temperature (°C)	-40 ~ + 85
MIL-STD-883K, Condition B MIL-STD-810G, Method 514.6, Procedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7 Operating Voltage 5V ± 10% Power Consumption Active mode: 590 mA / Idle mode: 100 mA Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Storage Temperature (°C)	-55 ~ + 100
VibrationProcedure I, Category 24 MIL-STD-810G, Method 514.6, Procedure I, Category 7Operating Voltage5V ± 10%Power ConsumptionActive mode: 590 mA / Idle mode: 100 mADimension (L x W x H)100.00 x 69.84 x 9.30 (mm)	Shock	
Power Consumption Active mode: 590 mA / Idle mode: 100 mA 100.00 x 69.84 x 9.30 (mm)	Vibration	Procedure I, Category 24 MIL-STD-810G, Method 514.6,
Dimension (L x W x H) 100.00 x 69.84 x 9.30 (mm)	Operating Voltage	5V ± 10%
	Power Consumption	Active mode: 590 mA / Idle mode: 100 mA
MTBF (hours) >5,000,000	Dimension (L x W x H)	100.00 x 69.84 x 9.30 (mm)
	MTBF (hours)	>5,000,000



Mechanical Specification



Unit: mm

For more information, contact your Apacer representative

Global Presence

Taiwan (Headquarters)
Apacer Technology Inc.
Tel: +886-2-2267-8000
Fax: +886-2-2267-2261

Apacer Technology B.V. Tel: +31-40-267-0000 Fax: +31-40-290-0686 Apacer Memory America, Inc. Tel: +1-408-518-8699 Fax: 1-510-249-9551 China Apacer Electronic(Shanghai) Co., Ltd.

an Ir

Apacer Technology Corp. Tel: +81-3-5419-2668 Fax: +81-3-5419-0018 Apacer Technologies Pvt. Ltd. Tel: +91-80-41529061~3 Fax: +91-80-41700215 Tel: +86-21-6228-9939